

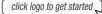
Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.41 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS





| PRIMARY CHARACTERISTICS | | | | | |
|--|-------------------------------|--|--|--|--|
| I _{F(AV)} | 2 x 7.5 A | | | | |
| V_{RRM} | 45 V | | | | |
| I _{FSM} | 100 A | | | | |
| V_F at $I_F = 7.5$ A | 0.49 V | | | | |
| T _{OP} max. (AC mode) | 150 °C | | | | |
| T _J max. (DC forward current) | 200 °C | | | | |
| Package | D ² PAK (TO-263AB) | | | | |
| Circuit configurations | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|--|------------|-------------------------------------|-------------|------|--|--|--|
| PARAMETER | | SYMBOL | VBT1545CBP | UNIT | | | |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 45 | V | | | |
| Maximum average forward rectified current (fig. 1) | per device | I (1) | 15 | Α | | | |
| | per diode | - I _{F(AV)} ⁽¹⁾ | 7.5 | | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | | 100 | Α | | | |
| Operating junction and storage temperature range (AC mode) | | | -40 to +150 | °C | | | |
| Junction temperature in DC forward current without reverse bias, t ≤ 1 h | | T _J ⁽²⁾ | ≤ 200 | °C | | | |

Notes

- (1) With heatsink
- (2) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|------------------------|--|-------------------------------|------|------|------|--|
| PARAMETER | TEST CC | TEST CONDITIONS | | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C T _A = 125 °C | V _F ⁽¹⁾ | 0.49 | - | V | |
| | I _F = 7.5 A | | | 0.55 | 0.63 | | |
| | I _F = 5 A | | | 0.41 | - | | |
| | I _F = 7.5 A | | | 0.49 | 0.57 | | |
| Reverse current per diode | \/ 4E\/ | T _A = 25 °C | I _R ⁽²⁾ | - | 500 | μΑ | |
| | V _R = 45 V | T _A = 125 °C | | 5 | 15 | mA | |

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|----------------|------------|------|--|
| PARAMETER | | SYMBOL | VBT1545CBP | UNIT | |
| Typical thermal resistance | per diode | $R_{	heta JC}$ | 3.5 | °C/W | |
| | per device | | 2.5 | C/VV | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-263AB | VBT1545CBP-E3/4W | 1.38 | 4W | 50/tube | Tube | |
| TO-263AB | VBT1545CBP-E3/8W | 1.38 | 8W | 800/reel | Tape and reel | |

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

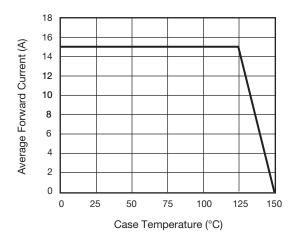


Fig. 1 - Maximum Forward Current Derating Curve

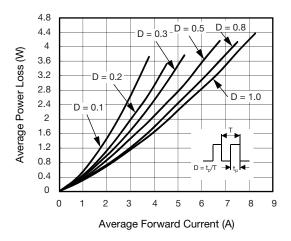


Fig. 2 - Forward Power Loss Characteristics Per Diode

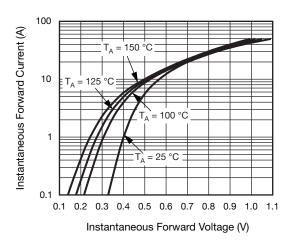


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

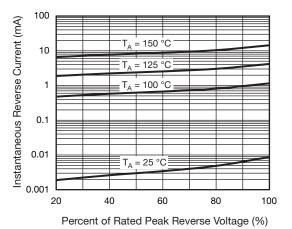


Fig. 4 - Typical Reverse Characteristics Per Diode



0.095 (2.41)

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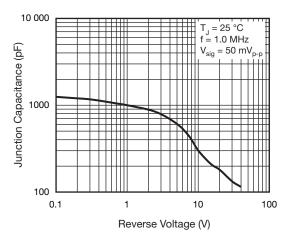


Fig. 5 - Typical Junction Capacitance Per Diode

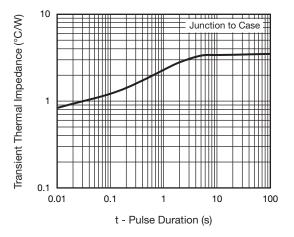


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

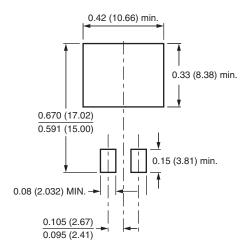
D²PAK (TO-263AB)

0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.045 (1.14) 0.245 (6.22) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56)

0.205 (5.20)

0.195 (4.95)

Mounting Pad Layout



0.110 (2.79)



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